

Substitute Form PTO-1449  
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Attorney's Docket No.

06816-035003

Application No.

09/825,875

**Information Disclosure Statement  
by Applicant**

(Use several sheets if necessary)

Applicant

Sarath Gunapala et al.

Filing Date

April 3, 2001

Group Art Unit

2811

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35 U.S.C. § 1.98(b)

PATENT & TRADEMARK OFFICE

**U.S. Patent Documents**

Examiner Initial	Desig. ID	Patent Number	Issue Date	Patentee	Class	Subclass	Filing Date If Appropriate
<i>DHK</i>	AA	5,488,504	Jan 30, 1996	Worchesky et al.			
	AB						
	AC						
	AD						
	AE						

**Foreign Patent Documents or Published Foreign Patent Applications**

Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
	AF						Yes	No

**Other Documents (include Author, Title, Date, and Place of Publication)**

Examiner Initial	Desig. ID	Document
<i>DHK</i>	AG	Gunapala, S.D., et al., "High Performance InGaAs/GaAs Quantum Well Infrared Photodetectors", <u>Applied Physics Letters</u> , Vol. 64, No. 25, 20 June 1994, pp. 3431-3433
<i>DHK</i>	AH	Nishiguchi, Masanori et al., "Mass Production Back-Grinding/Wafer-Thinning Technology for GaAs Devices", <u>IEEE Transactions on Components, Hybrids, and Manufacturing Technology</u> , Vol. 13, No. 3, September, 1990, pp. 528-533
	AI	
	AJ	

Examiner Signature

*Kang Donghee*

Date Considered

*2-24-03*

EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.